

Amendments to the Specification:

Please amend the specification as follows:

Please amend the second full paragraph on page 3 as follows:

A structure appropriable for all the TFTs described below has not been established: A pixel TFT which is required to have a high withstanding voltage ~~high-pressure-resistant~~ characteristic as well as to lower an off-current, a TFT for a driving circuit which is required to have a high withstanding voltage ~~high-pressure-resistant~~ characteristic as well as to raise an on-current, such as a buffer circuit, a shift register circuit, level shifter circuit, or a sampling circuit, or a TFT for a functional circuit, such as a CPU, a DRAM, an image processing circuit, or a sound processing circuit wherein a short channel structure and the decline in the threshold voltage arising therefrom are attached importance to.